Unit: mm

TOSHIBA Transistor Silicon PNP Epitaxial Type (PCT Process)

HN1A26FS

Frequency General-Purpose Amplifier Applications

 Two devices are incorporated into a fine-pitch, small-mold (6-pin) package.

High voltage: V_{CEO} = -50 V
High current: I_C = -100 mA (max)
High hee: hee = 120 to 400

Excellent h_{FE} linearity

: $h_{FE} (I_C = -0.1 \text{ mA})/h_{FE} (I_C = -2 \text{ mA}) = 0.95 \text{ (typ.)}$

Absolute Maximum Ratings (Ta = 25°C)

Characteristic	Symbol	Rating	Unit
Collector-base voltage	V_{CBO}	-50	V
Collector-emitter voltage	V_{CEO}	-50	V
Emitter-base voltage	V_{EBO}	- 5	V
Collector current	IC	-100	mA
Base current	ΙΒ	-30	mW
Collector power dissipation	P _C (Note 1)	50	mW
Junction temperature	Tj	150	°C
Storage temperature range	T _{stg}	−55 ~ 150	°C

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

1.0±0.05 0.1±0.05 0.8±0.05 0.1±0.0 0.15 ± 0.05 .0±0.05 0.7±0.05 35 0.1 ± 0.05 1.EMITTER1 2.BASE1 (B1) 3.COLLECTOR2 4.EMITTER2 (E2) fS6 5.BASE2 (B2)6.COLLECTOR1 (C1) **JEDEC** JEITA TOSHIBA 2-1F1D

Weight: 0.001g (typ.)

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: Total rating.

Note:

Electrical Characteristics (Ta = 25°C)

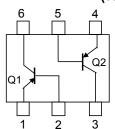
Characteristic	Symbol	Test Condition	Min	Тур.	Max	Unit
Collector cutoff current	I _{CBO}	$V_{CB} = -50 \text{ V}, I_{E} = 0$	_	_	-0.1	μΑ
Emitter cutoff current	I _{EBO}	$V_{EB} = -5 \text{ V}, I_{C} = 0$	_	_	-0.1	μΑ
DC current gain	h _{FE} (Note)	$V_{CE} = -6 \text{ V}, I_{C} = -2 \text{ mA}$	120	_	400	
Collector-emitter saturation voltage	V _{CE (sat)}	$I_C = -100 \text{ mA}, I_B = -10 \text{ mA}$	_	-0.18	-0.3	V
Transition frequency	f⊤	$V_{CE} = -10 \text{ V}, I_{C} = -1 \text{ mA}$	80	_	_	MHz
Collector output capacitance	C _{ob}	$V_{CB} = -10 \text{ V}, I_E = 0, f = 1 \text{ MHz}$	_	1.6	_	pF

Note: hFE Classification

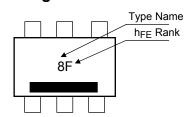
Y (F): 120 ~ 140, GR (H): 200 ~ 400

() Marking symbol

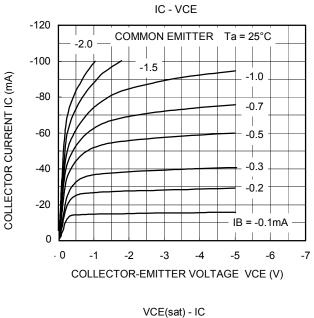
Equivalent Circuit (top view)

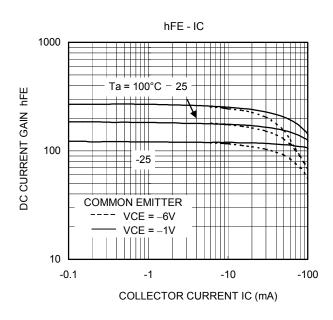


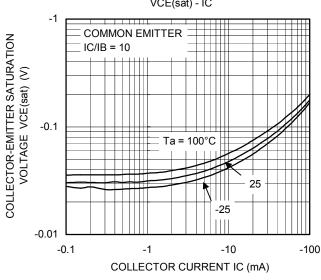
Marking

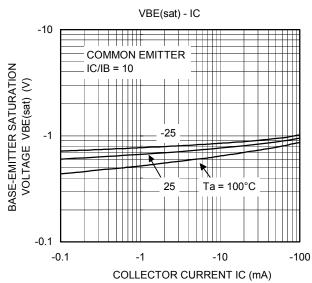


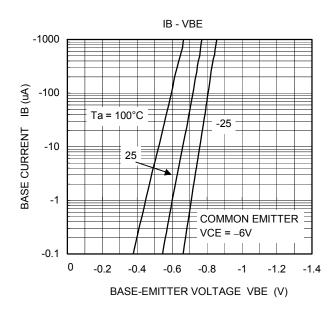
Q1, Q2 Common

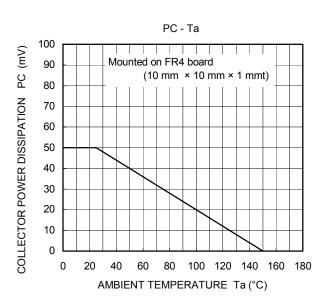












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20070701-EN GENERAL

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